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産業技術総合研究所　ナノカーボンデバイス研究センター 山田　貴壽

(1) 原著論文

(ア) 筆頭原著招待論文

1. T. Yamada, M. Ishihara, J. Kim and M. Hasegawa, “Low temperature graphene synthesis by microwave plasma CVD”, *J. Phys. D* **46** (2013) 063001. (**Most read Most cited Latest articles, Select articles, Review articles)**
2. T. Yamada, H. Yamaguchi, K. Okano and A. Sawabe, “Field emission from boron and phosphorus doped diamond”, *New Diamond and Frontier Carbon Technology* **15** (2005) 337.
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1. T. Yamada, Y. Okigawa, M. Hasegawa, K. Watanabe and T. Taniguchi, “Relationship between mobility and strain in CVD graphene on h-BN”, *AIP Adv.* **10**, 085309 (2020). **(Feature article, cover picture)**
2. T. Yamada and T. Masuzawa, “Field emission from potassium-doped vertically aligned carbon nanosheet”, *Vacuum* **167**, 64 (2019).
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11. T. Yamada, M. Ishihara and M. Hasegawa, “Large area coating of graphene at low temperature using a roll-to-roll microwave plasma chemical vapor deposition”, *Thin Solid Films* **532** (2013) 89-93.
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